NSN 5961-01-229-0347

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View Online at https://aerobasegroup.com/nsn/5961-01-229-0347 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **End Application:** Missile, minuteman lgm-30 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204aa **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 collector to emitter voltage, dc with specified circuit between base and emitter and 450.0 collector-to-emitter, substaining voltage, base open-circuited and 7.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 15.00 amperes source cutoff current **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn. Weapon system essential **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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